## NSN 5962-01-345-1142

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View Online at https://aerobasegroup.com/nsn/5962-01-345-1142 **Overall Length:** 0.840 inches **Overall Height:** 0.400 inches **Body Length:** 0.840 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 739.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** 1260-01-165-3959 control-display sys **Features Provided:** Bipolar and schottky and w/active pull-up and high impedance and 3-state output and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** 

Transistor-transistor logic

**Input Circuit Pattern:** 

10 input

**Case Outline Source And Designator:** 

D-2 mil-m-38510

**Current Rating Per Characteristic:** 

130.00 milliamperes supply

**Terminal Surface Treatment:** 

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

**Time Rating Per Chacteristic:** 

75.00 nanoseconds propagation delay time, high to low level output and 75.00 nanoseconds propagation delay time, low to high level output

**Memory Device Type:** 

Prom

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quan	tity:
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16 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0